L Number	Hits	Search Text	DB	Time stamp
1	1	5939886.pn.	USPAT;	2002/09/18
			US-PGPUB	15:04
2	1	5939886.pn.	USPAT;	2002/09/18
			US-PGPUB	15:04
-	0	("1 and (voltage or volt)").PN.	USPAT;	2002/09/10
			US-PGPUB	10:12
-	93	156/345.28.ccls.	USPAT; US-PGPUB	12:09
	7.6	15.5 (2.45, 00, mm] - and (realthogo on realth)	USPAT;	2002/09/10
-	76	156/345.28.ccls. and (voltage or volt)	US-PGPUB	10:38
	41	(156/345.28.ccls. and (voltage or volt))	USPAT;	2002/09/10
_	41	and ((substrate or wafer) with voltage)	US-PGPUB	11:12
_	17	((156/345.28.ccls. and (voltage or volt))	USPAT;	2002/09/10
-		and ((substrate or wafer) with voltage))	US-PGPUB	11:12
		and impedance		
_	28	((156/345.28, 345.24, 345.13,	USPAT;	2002/09/11
		345.15).ccls. and (substrate or wafer)	US-PGPUB	08:58
	l	with voltage) not ((156/345.28).CCLS.)		
-	466	h011021/\$.ipc. and ((substrate or wafer)	USPAT;	2002/09/11
		with voltage) and impedance	US-PGPUB	12:14
-	153	c23c016/\$.ipc. and ((substrate or wafer)	USPAT;	2002/09/10
	_	with voltage) and impedance	US-PGPUB	13:00 2002/09/11
_	24	(118/712).ccls. and (substrate or wafer)	USPAT; US-PGPUB	11:23
	_	with voltage (118/712).ccls. and ((substrate or wafer)	USPAT;	2002/09/10
-	5	with voltage) and impedance	US-PGPUB	12:58
	607	(h011021/\$.ipc. and ((substrate or wafer)	USPAT;	2002/09/10
-	807	with voltage) and impedance) or	US-PGPUB	12:59
		(c23c016\\$.ipc. and ((substrate or wafer)		
		with voltage) and impedance)		
_	13		JPO;	2002/09/10
		with voltage) and impedance	DERWENT	13:00
_	102	h011021/\$.ipc. and ((substrate or wafer)	JPO;	2002/09/10
		with voltage) and impedance	DERWENT	13:01
-	105	(c23c016/\$.ipc. and ((substrate or wafer)	JPO;	2002/09/10
- 4*		with voltage) and impedance) or	DERWENT	14:19
		(h011021/\$.ipc. and ((substrate or wafer) with voltage) and impedance)		
	4170		USPAT;	2002/09/10
-	41/0	and voltage and current and impedance	US-PGPUB	18:30
_	1674		USPAT;	2002/09/10
	20,1	and voltage and current and impedance)	US-PGPUB	14:27
		and (vacuum or exhaust) and semiconductor		
-	93		USPAT;	2002/09/10
			US-PGPUB	19:07
-	237		USPAT;	2002/09/10 19:11
		voltage) and current and impedance and	US-PGPUB	19.11
		semiconductor and vacuum and probe (("5198072") or ("5444259") or	USPAT;	2002/09/11
-	6	("5198072") or ("5444239") or ("5711843")	US-PGPUB	08:50
		or ("5830310")).PN.	32 232 2	
	69	1	USPAT;	2002/09/11
		345.15).ccls. and (substrate or wafer)	US-PGPUB	10:41
		with voltage		
-	31	(substrate or wafer) with (rear or back	USPAT;	2002/09/11
		adj side) with voltage and probe	US-PGPUB	11:22
_	72		USPAT;	2002/09/11
		same (Film adj thickness)	US-PGPUB	12:13 2002/09/11
-	27912	hitachi.as.	USPAT; US-PGPUB	12:13
		hitachi on and //auhatmata on wafer	USPAT;	2002/09/11
-	427	hitachi.as. and ((substrate or wafer)	US-PGPUB	12:15
		with voltage) and impedance	03-16100	1 12.10